**TOSHIBA TA4103F** 

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT SILICON MONOLITHIC

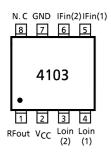
# TA4103F

# 1.9GHz BAND UP CONVERTER APPLICATION

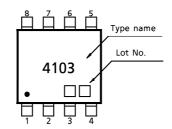
#### **FEATURES**

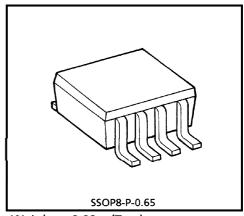
- Built in Lo and IF buffer amplifiers.
- Double balanced MIX circuit
- High conversion gain:  $G_C = 3dB$  (Typ.)
- Recommended operating voltage:  $V_{CC} = 2.7 \sim 3.3 \text{V}$

#### PIN ASSIGNMENT (Topview)



### **MARKING**





Weight: 0.02g (Typ.)

### MAXIMUM RATING (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	VCC	5	٧
Total Power Dissipation	P <sub>D</sub> (*)	300	mW
Operating Temperature	T <sub>opr</sub>	<b>- 40∼8</b> 5	°C
Storage Temperature Range	T <sub>stg</sub>	<b>-</b> 55∼125	°C

(\*) When mounted on the glass epoxy board of 2.5cm<sup>2</sup> x 1.6t.

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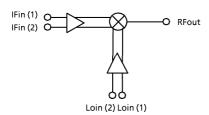
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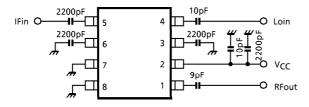
CHARACTERISTIC	SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
RF Frequency Range	fRFout			1895	_	1918	MHz
IF Frequency Range	fIFin	1 —		220	_	250	MHz
Lo Frequency Range	fLoin			1645	_	1698	MHz
Circuit Current	lcc	_	Non Carrier	23	26.5	33	mA
Conversion Gain	GC		PLoin = - 20dBmW	1	3	_	dB
Output Power At 1dB Gaing Compression	Po1dB	1		- 19	- 17	_	dB
Lo-RF Leakage Power	PRFLo			_	_	- 20	dBmW
Lo-IF Leakege Power	PIFLo			_	_	- 33	dBmW
Adjacent Channel Leakage Power Ratio	Padj		$P_{RFout} = -18dBmW$ $P_{IFin} = Adjusted$ $\Delta f = 600kHz$ (Note)	_	- 63	_	dB

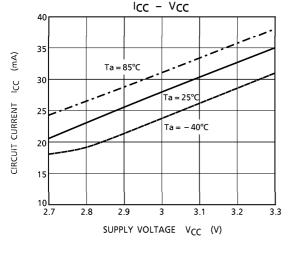
(Note) Input signal is modulated to  $\pi/4QPSK$  ( $\alpha=0.5$ ). Bit rate is 384 kbps.

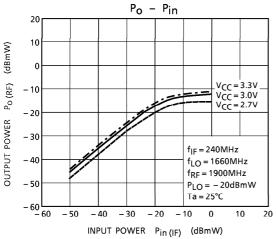
# **BLOCK DIAGRAM**

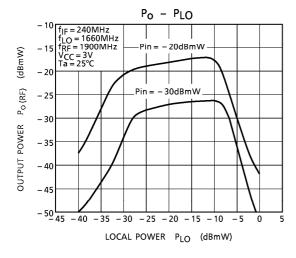


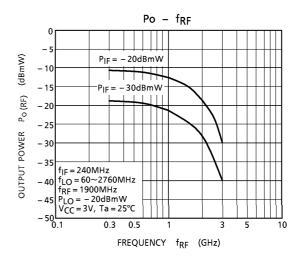
# **TEST CIRCUIT 1**

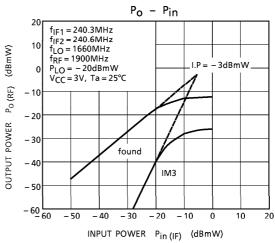


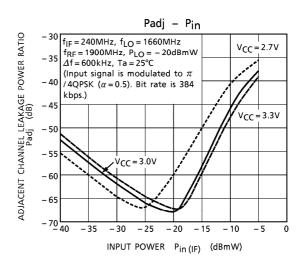






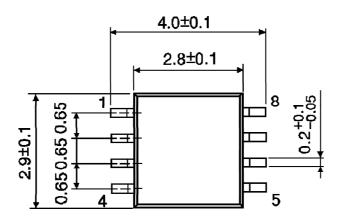


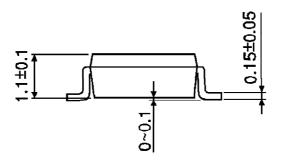




## OUTLINE DRAWING SSOP8-P-0.65

Unit: mm





Weight: 0.02g (Typ.)